



## MBR60060CT

|                                |  |
|--------------------------------|--|
| <b>Hersteller-Teilenummer:</b> | MBR60060CT   |
| <b>Hersteller / Marke:</b>     | GeneSiC Semiconductor  |
| <b>Teil der Beschreibung:</b>  | DIODE MODULE 60V 300A 2TOWER   |
| <b>Datenblätter:</b>           | <a href="#">1.MBR60060CT.pdf</a><br><a href="#">2.MBR60060CT.pdf</a> |
| <b>RoHS Status:</b>            | Bleifrei / RoHS-konform  |
| <b>Lagerzustand:</b>           | New original, 2540 pcs Stock Available.                              |
| <b>Liefern von:</b>            | Hong Kong  |
| <b>Versandweg:</b>             | DHL/Fedex/TNT/UPS/EMS  |

Image may be representation.  
See specs for product details.

### Spezifikationen

|                                    |   |
|------------------------------------|---|
| Artikelnummer                      | MBR60060CT  |
| Hersteller                         | GeneSiC Semiconductor                               |
| Beschreibung                       | DIODE MODULE 60V 300A 2TOWER                        |
| Kategorie                          | Diskrete Halbleiterprodukte > Dioden-Gleichrichter- |
| Teilstatus                         | 2540 pcs Stock                                      |
| Spannung - Forward (Vf) (Max) @ If | 800mV @ 300A  |
| Spannung - Sperr (Vr) (max)        | 60V   |
| Supplier Device-Gehäuse            | Twin Tower  |
| Geschwindigkeit                    | Fast Recovery = 200mA (Io)                          |
| Serie                              | -   |
| Verpackung                         | Bulk  |
| Verpackung / Gehäuse               | Twin Tower  |
| Betriebstemperatur - Anschluss     | -50°C ~ 150°C                                       |
| Befestigungsart                    | Chassis Mount                                       |
| Diodentyp                          | Schottky  |
| Diodenkonfiguration                | 1 Pair Common Cathode                               |
| Strom - Sperrleckstrom @ Vr        | 1mA @ 20V   |
| Strom - Richt (Io) (pro Diode)     | 300A  |

### Sie können auch interessiert

sein:



**MBR60100**  
GeneSiC Semiconductor  
DIODE SCHOTTKY 100V 60A DO5



**MBR60045CTL**  
GeneSiC Semiconductor  
DIODE SCHOTTKY 45V 300A 2 TOWER



**MBR60045CT**  
GeneSiC Semiconductor  
DIODE MODULE 45V 300A 2TOWER



**MBR60100CT**  
SMC Diode Solutions  
DIODE ARRAY SCHOTTKY 100V TO220



**MBR60060CTR**  
GeneSiC Semiconductor  
DIODE MODULE 60V 300A 2TOWER



**MBR60080CTR**  
GeneSiC Semiconductor  
DIODE MODULE 80V 300A 2TOWER



**MBR60045CTR**  
GeneSiC Semiconductor  
DIODE MODULE 45V 300A 2TOWER



**MBR60045CTRL**  
GeneSiC Semiconductor  
DIODE SCHOTTKY 45V 300A 2 TOWER

### MBR60060CT Zugehöriges

Mehr

### Schlüsselwort

|                                  |                        |                         |                  |                                  |
|----------------------------------|------------------------|-------------------------|------------------|----------------------------------|
| MBR60060CT GeneSiC Semiconductor | MBR60060CT Datenblatt  | MBR60060CT-Datenblätter | MBR60060CT PDF   | GeneSiC Semiconductor MBR60060CT |
| MBR60060CT Electronic            | MBR60060CT-Komponenten | MBR60060CT-Verteiler    | MBR60060CT-Bild  | MBR60060CT-Teil                  |
| MBR60060CT Preis                 | MBR60060CT Hersteller  | MBR60060CT Bild         | MBR60060CT Aktie | MBR60060CT Inventar              |
| MBR60060CT Neu                   | MBR60060CT Original    | MBR60060CT garantiert   | MBR60060CT RFQ   | MBR60060CT Online bestellen      |

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